NSN 5961-01-014-0682

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Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-014-0682 **Inclosure Material:** Metal **Overall Length:** 0.370 inches **Overall Diameter:** 0.820 inches **Mounting Facility Quantity: Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 50.0 repetitive peak reverse voltage, peak total value and 200.0 repetitive peak off-state voltage **Current Rating Per Characteristic:** 25.00 amperes source cutoff current **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector peak **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No